RoHS

COMPLIANT

HALOGEN

FREE

Vishay Semiconductors

High Performance Schottky Rectifier, 19 A



www.vishay.com

PRIMARY CHARACTERISTICS					
I _{F(AV)}	19 A				
V _R	15 V				
V _F at I _F	0.32 V				
I _{RM} max.	522 mA at 100 °C				
T _J max.	125 °C				
E _{AS}	6.75 mJ				
Package	TO-220AC 2L				
Circuit configuration	Single				

FEATURES

- 125 °C T_J operation ($V_R < 5 V$)
- Optimized for OR-ing applications
- Ultralow forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-19TQ015... Schottky rectifier has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	19	А			
V _{RRM}		15	V			
I _{FSM}	t _p = 5 μs sine	700	А			
V _F	19 A _{pk} , T _J = 75 °C	0.32	V			
TJ	Range	-55 to +125	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-19TQ015-M3	UNITS			
Maximum DC reverse voltage	V _R	15	V			
Maximum working peak reverse voltage	V _{RWM}	15	v			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at $T_C = 80$ °C,	19				
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	700	А		
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	330			
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 1.50 \text{ A}, L = 6 \text{ I}$	6.75	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim		1.50	А		

Revision: 22-Dec-2021

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

1



www.vishay.com

Vishay Semiconductors

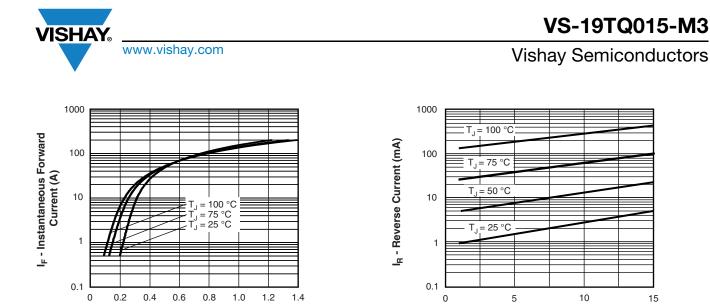
ATRIA		TIONS

PARAMETER	SYMBOL	TEST CO	VALUES	UNITS	
		19 A	T 05 00	0.36	v
Maximum forward voltage drop	V (1)	38 A	T _J = 25 °C	0.46	
See fig. 1	V _{FM} ⁽¹⁾	19 A	T 75 %O	0.32	
		38 A	T _J = 75 °C	0.43	
		T _J = 100 °C, V _R = 12 V		465	0
Maximum reverse leakage current	. (1)	T _J = 100 °C, V _R = 5 V		285	
See fig. 2	I _{RM} ⁽¹⁾	T _J = 25 °C		10.5	mA
		T _J = 100 °C	$V_{R} = Rated V_{R}$	522	
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		2000	pF
Typical series inductance	Ls	Measured lead to lead 5 mm from package body		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperat	ture range	TJ		-55 to 125	°C		
Maximum storage temperat	ure range	T _{Stg}		-55 to 150			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	1.50	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	nooth and greased 0.50			
Approximate weight				2	g		
				0.07	oz.		
Mounting torque	minimum			6 (5)	kgf · cm		
Mounting torque –	maximum			12 (10)	(lbf · in)		
Marking device	king device Case style 2L TO-220AC 197		015				



V_{FM} - Forward Voltage Drop (V) Fig. 1 - Maximum Forward Voltage Drop Characteristics



15

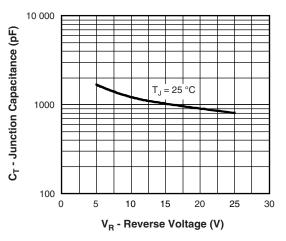
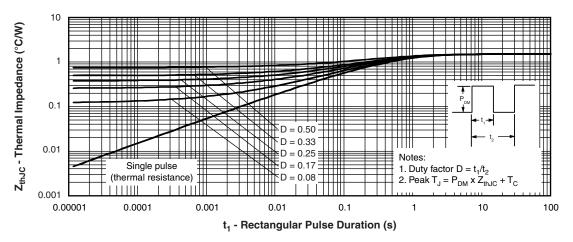


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

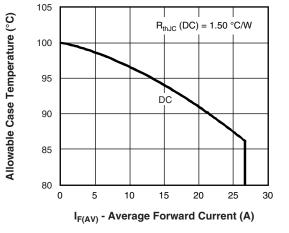




Revision: 22-Dec-2021 Document Number: 94151 3 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay Semiconductors



www.vishay.com

SHAY

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

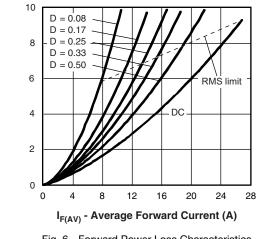


Fig. 6 - Forward Power Loss Characteristics

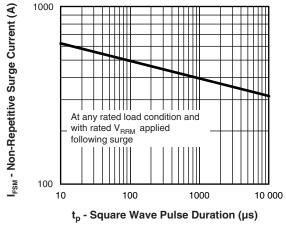


Fig. 7 - Maximum Non-Repetitive Surge Current

Average Power Loss (W)

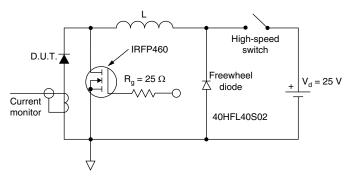
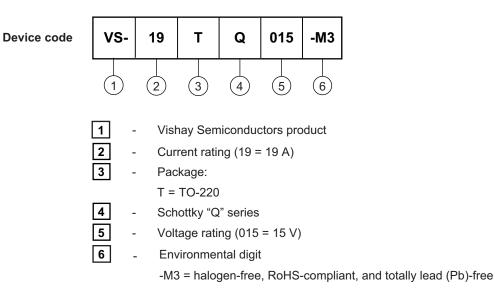


Fig. 8 - Unclamped Inductive Test Circuit

Vishay Semiconductors

SHAY www.vishay.com

ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY PACKAGING DESCRIPTION					
VS-19TQ015-M3	50	Antistatic plastic tubes				

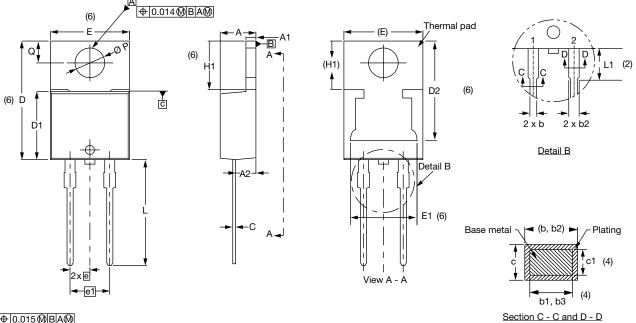
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96156					
Part marking information	www.vishay.com/doc?95391				
SPICE model	www.vishay.com/doc?96005				



Vishay Semiconductors

TO-220AC 2L

DIMENSIONS in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIN	MILLIMETERS		INCHES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Conforms to JEDEC[®] outline TO-220AC

Notes

⁽²⁾ Lead dimension and finish uncontrolled in L1

(4) Dimension b1, b3, and c1 apply to base metal only

- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

Revision: 07-Mar-2022

1

Document Number: 96156

 $^{^{(1)}\,}$ Dimensioning and tolerancing as per ASME Y14.5M-1994 $\,$

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁵⁾ Controlling dimensions: inches



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.